DESCRIPTION

The 1N4001F~1N4007F are available in SMAF package

FEATURES

- For surface mounted applications
- Low profile package
- Glass Passivated Chip Junction
- Easy to pick and place
- Available in SMAF package

ORDERING INFORMATION

Package Type	Part Number				
	1N4001F				
	1N4002F				
SMAF	1N4003F				
	1N4004F 1N4005F				
					1N4006F
	1N4007F				
	Note	SPQ: 3,000pcs/Reel			
AiT provides all RoHS Compliant Products					

MECHANICAL DATA

Case: SMAF

Terminals: Solderable per MIL-STD-750,

Method 2026

Approx. Weight: 27mg 0.00086oz

PIN DESCRIPTION



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified. Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.

Paramete	er	Symbol	1N4001F	1N4002F	1N4003F	1N4004F	1N4005F	1N4006F	1N4007F	Unit
Maximum Repetitive	Peak	V _{RRM}	50	400	000	400	600	000	4000	V
Reverse Voltage	Reverse Voltage		50	100	200	400	600	800	1000	V
Maximum RMS Volta	ge	V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blockin	ng Voltage	V _{DC}	50	100	200	400	600	800	1000	V
Maximum Average Fo	orward	I _{F(AV)}								
Rectified Current at T	Rectified Current at T _A =65°C		1							Α
Peak Forward Surge	Current									
8.3ms Single Half Sine Wave		I _{FSM}	30							A
Superimposed on Rated Load										
(JEDEC Method)	(JEDEC Method)									
Maximum Instantaneous Forward		.,	1.1							V
Voltage at 1A		V _F								
Maximum DC										
Reverse Current	T _A =25°C		5 50							uA
at Rated DC	T _A =125°C	l _R								
Blocking Voltage										
Typical Junction CapacitanceNOTE1		СJ	9						pF	
Typical Thermal ResistanceNOTE2		R ₀ JA	115						°C/W	
Operating and Storage		TJ,	-55 ~+150							00
Temperature Range		T _{STG}							°C	

NOTE1: Measured at 1MHz and applied reverse voltage of 4 V D.C.

NOTE2: Thermal resistance from junction to ambient at 0.375" (9.5 mm) lead length, P.C.B. mounted

REVERSE VOLTAGE 50V TO 1000V FORWARD CURRENT 1A

TYPICAL CHARACTERISTICS

Figure. 1 Forward Current Derating Curve

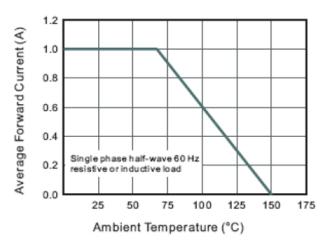


Figure. 3 Typical Forward Characteristic

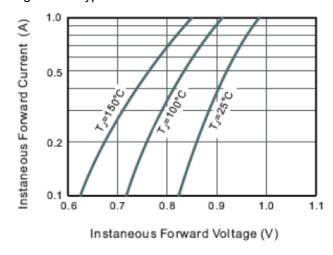


Figure. 2 Typical Instantaneous Reverse Characteristics

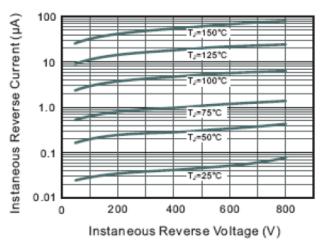
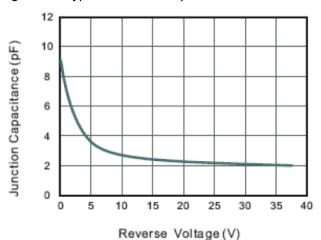


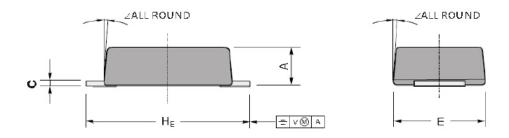
Figure. 4 Typical Junction Capacitance

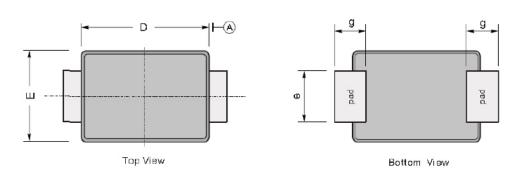


PACKAGE INFORMATION

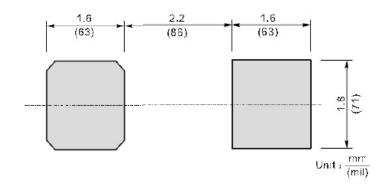
Dimension in SMAF (Unit: mm)

Plastic surface mounted package; 2 leads





The recommended mounting pad size



UN	NIT	Α	С	D	Е	e	g	HE	∠	
mm	Max	1.1	0.20	3.7	2.7	1.6	1.2	4.9		
	Min	0.9	0.12	3.3	2.4	1.3	0.8	4.4	70	
mil	Max	43	7.9	146	106	63	47	193	7°	
	Min	35	4.7	130	94	51	31	173		



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